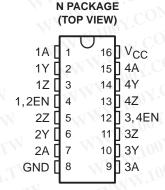
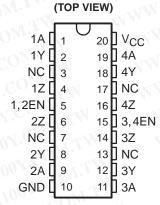
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- Meets or Exceeds the Requirements of ANSI Standards EIA/TIA-422-B and RS-485 and ITU Recommendation V.11.
- Designed for Multipoint Transmission on Long Bus Lines in Noisy Environments
- 3-State Outputs
- Common-Mode Output Voltage Range of –7 V to 12 V
- Active-High Enable
- Thermal Shutdown Protection
- Positive- and Negative-Current Limiting
- Operates From Single 5-V Supply
- Low Power Requirements
- Functionally Interchangeable With MC3487

description

The SN75174 is a monolithic quadruple differential line driver with 3-state outputs. It is designed to meet the requirements of ANSI Standards EIA/TIA-422-B and RS-485 and ITU Recommendation V.11. The device is optimized for balanced multipoint bus transmission at rates up to 4 megabaud. Each driver features wide positive and negative common-mode output voltage ranges making it suitable for party-line applications in noisy environments.





DW PACKAGE

NC - No internal connection

The SN75174 provides positive- and negative-current limiting and thermal shutdown for protection from line fault conditions on the transmission bus line. Shutdown occurs at a junction temperature of approximately 150°C. This device offers optimum performance when used with the SN75173 or SN75175 quadruple differential line receivers.

The SN75174 is characterized for operation from 0°C to 70°C.

FUNCTION TABLE (each driver)

INP	100	ENABLE	OUTPUTS		
INF	110	ENABLE	Y	Z	
W	ł	MH.	Н	L	
L	W.T.	H CC	L	Н	
\rightarrow		100 L	Z	Z	

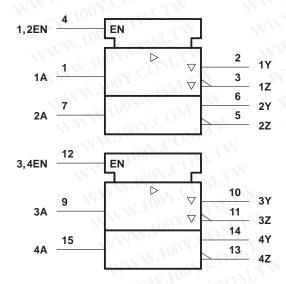
H = TTL high level, X = irrelevant, L = TTL low level, Z = high impedance (off) 勝 特 力 材 料 886-3-5753170 胜特力电子(上海) 86-21-54151736 胜特力电子(深圳) 86-755-83298787 Http://www.100y.com.tw



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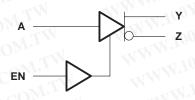


logic symbol†



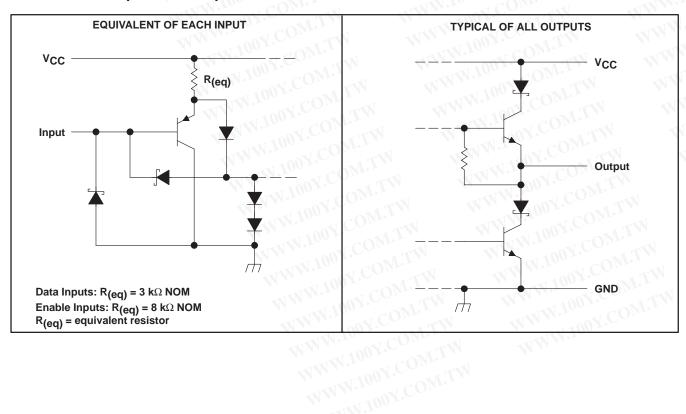
† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram, each driver (positive logic)



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schematics of inputs and outputs



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absolute maximum ratings over operating free-air temperature (unless otherwise noted)†

Supply voltage, V _{CC} (see Note 1)	
Output voltage range, V _O	
Input voltage, V _I	
Continuous total dissipation	
Operating free-air temperature range, T _A	0°C to 70°C
Storage temperature range, T _{sta}	65°C to 150°C
Lead temperature 1.6 mm (1/16 inch) from case for 10 seconds	260°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: All voltage values are with respect to the network ground terminal.

DISSIPATION RATING TABLE

PACKAGE	T _A ≤ 25°C POWER RATING	DERATING FACTOR ABOVE T _A = 25°C	T _A = 70°C POWER RATING
DW	1125 mW	9.0 mW/°C	720 mW
N N	1150 mW	9.2 mW/°C	736 mW

recommended operating conditions

N 1150 mW 9.2 mW/°C	73	6 mVV		bo.
recommended operating conditions				
AN TOP SOME SALES TO MAN TOP TO COMP.	MIN	NOM	MAX	UNIT
Supply voltage, V _{CC}	4.75	5	5.25	V
High-level input voltage, VIH	2		M.	V
Low-level input voltage, V _{IL}	TW		0.8	V
Common-mode output voltage, V _{OC}	1.	<u> </u>	7 to 12	V
High-level output current, IOH	Mir	-<1	-60	mA
Low-level output current, IOL	T.Mc	AA	60	mA
Operating free-air temperature, T _A	0	TW	70	√°C



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electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER	TES	CONDITIONS	MIN	TYP [†]	MAX	UNIT
VIK	Input clamp voltage	$I_{I} = -18 \text{ mA}$	CON	-xIW	W.In.	-1.5	V
Vон	High-level output voltage	$V_{IH} = 2 V$, $I_{OH} = -33 m$.	V _{IL} = 0.8 V,	WY	3.7	10 ^Y .C	O V
VOL	Low-level output voltage	V _{IH} = 2 V, I _{OL} = 33 mA	V _{IL} = 0.8 V,	W	1.1	100X	V
VO	Output voltage	$I_O = 0$	1001: MITH	0	N	106	V
V _{OD1}	Differential output voltage	I _O = 0	ON COMMENT	1.5	6	6	V
V _{OD2}	Differential output voltage	R _L = 100 Ω,	See Figure 1	1/2 V _{OD1} or 2 [‡]	WW	M.10	OVC
		$R_L = 54 \Omega$,	See Figure 1	1.5	2.5	5	O V°
V _{OD3}	Differential output voltage	See Note 2	M. Co.	1.5	W	5	V
Δ V _{OD}	Change in magnitude of differential output voltage§	W	MAN' TOOX' COM	WT.	V	±0.2	1100
Voc	Common-mode output voltage¶	R_L = 54 Ω or 100 Ω , See Figure 1		M.TW		+3 -1	W.V0
ΔIVOCI	Change in magnitude of common-mode output voltage§			OMITY		±0.2	V
IO	Output current with power off	$V_{CC} = 0$,	$V_0 = -7 \text{ V to } 12 \text{ V}$	On T	W	±100	μΑ
loz	High-impedance-state output current	$V_O = -7 \text{ V to}$	12 V	CO_{Mr}	-XX	±100	μΑ
ΊΗ	High-level input current	V _I = 2.7 V	W. 1003	COM.	1.4.	20	μΑ
I _I L	Low-level input current	V _I = 0.5 V	1/1/1/100	1.00	IN	-360	μΑ
los	Short-circuit output current	$V_O = -7 V$ $V_O = V_{CC}$		V.Co.	WT	-180	mA
				ow CO	NI.	180	
		V _O = 12 V	O = 12 V		Mi	500	
la a	Supply current (all drivers)	No load	Outputs enabled	1007	38	60	mA
ICC		Outputs disabled		LOON.C	18	40	mA

[†] All typical values are at $V_{CC} = 5 \text{ V}$ and $T_A = 25^{\circ}\text{C}$.

NOTE 2: See EIA Standard RS-485.

switching characteristics, $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$

	PARAMETER	TEST (CONDITIONS	MIN TYP	MAX	UNIT
t _{d(OD)} Differential-output delay time		$R_1 = 54 \Omega$, See Figure 2		45	65	ns
t _t (OD)	Differential-output transition time	$R_L = 54 \Omega$,	See Figure 2	80	120	ns
^t PZH	Output enable time to high level	$R_L = 110 \Omega$,	See Figure 3	80	120	ns
tpzL	Output enable time to low level	$R_L = 110 \Omega$,	See Figure 4	55	80	ns
^t PHZ	Output disable time from high level	$R_L = 110 \Omega$,	See Figure 3	75	115	ns
tPLZ	Output disable time from low level	$R_L = 110 \Omega$,	See Figure 3	18	30	ns



[‡] The minimum V_{OD2} with a 100- Ω load is either 1/2 V_{OD1} or 2 V, whichever is greater.

 $[\]Delta V_{OD}$ and ΔV_{OC} are the changes in magnitude of V_{OD} and V_{OC} , respectively, that occur when the input is changed from a high level to a low level.

 $[\]P$ In ANSI Standard EIA/TIA-422-B, V_{OC}, which is the average of the two output voltages with respect to ground, is called output offset voltage, Vos.

SYMBOL EQUIVALENTS

DATA SHEET PARAMETER	EIA/TIA-422-B	RS-485
COMP VO	V _{oa} , V _{ob}	V _{oa} , V _{ob}
V _{OD1}	V _o	V _o
IV _{OD2} I	$V_t (R_L = 100 \Omega)$	$V_t (R_L = 54 \Omega)$
IV _{OD3} I	WWW.100Y.COM.T	V _t (Test Termination) Measurement 2)
Δ V _{OD}	$ V_t - \overline{V}_t $	$ V_t - \overline{V}_t $
Voc	V _{os}	V _{os}
ΔIVOCI	$ V_{OS} - \overline{V}_{OS} $	$ V_{OS} - \overline{V}_{OS} $
los	I _{sa} , I _{sb}	W. T. W.
IO N. TO	$ I_{xa} , I_{xb} $	l _{ia} ,l _{ib}

PARAMETER MEASUREMENT INFORMATION

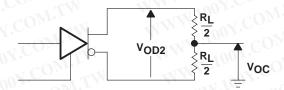
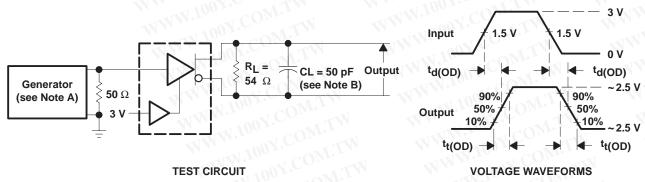


Figure 1. Differential and Common-Mode Output Voltages



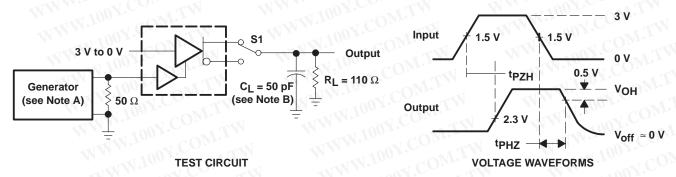
NOTES: A. The input pulse is supplied by a generator having the following characteristics: $t_r \le 5$ ns, $t_f \le 5$ ns, $PRR \le 1$ MHz, duty cycle = 50%, $Z_Q = 50 \Omega$.

B. C_L includes probe and stray capacitance.

Figure 2. Differential-Output Test Circuit and Voltage Waveforms



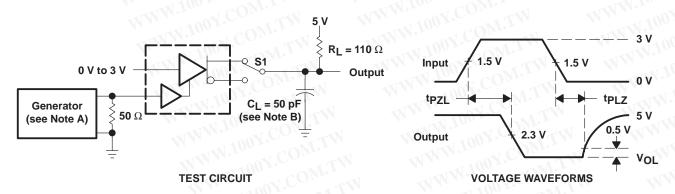
PARAMETER MEASUREMENT INFORMATION



NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR \leq 1 MHz, duty cycle = 50%, $t_f \leq$ 5 ns, $Z_O = 50 \ \Omega$.

B. C_L includes probe and stray capacitance.

Figure 3. Test Circuit and Voltage Waveforms



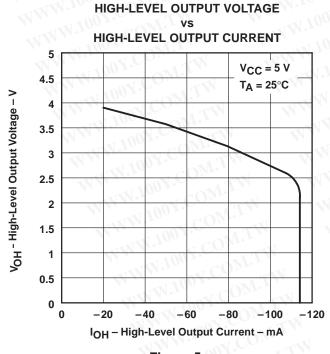
NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR \leq 1 MHz, duty cycle = 50%, $t_f \leq$ 5 ns, $Z_O = 50 \ \Omega$.

B. C_L includes probe and stray capacitance.

Figure 4. Test Circuit and Voltage Waveforms



TYPICAL CHARACTERISTICS



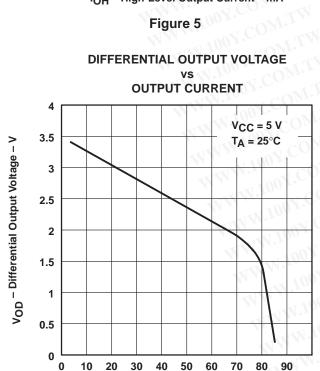


Figure 7

IO - Output Current - mA

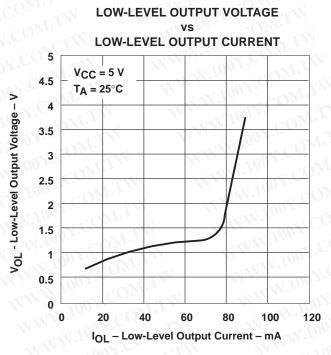


Figure 6

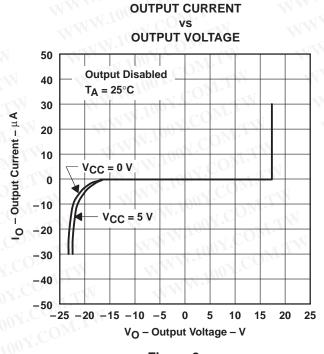
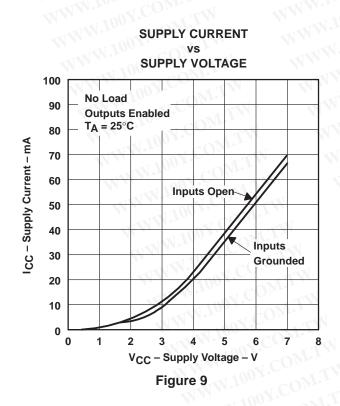
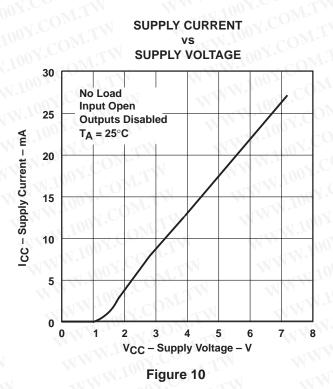


Figure 8

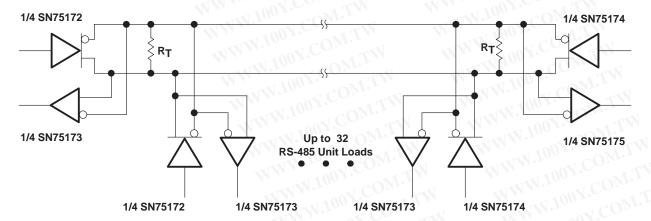


TYPICAL CHARACTERISTICS





APPLICATION INFORMATION



NOTE: The line length should be terminated at both ends in its characteristic impedance (R_T = Z_O). Stub lengths off the main line should be kept as short as possible.

Figure 11. Typical Application Circuit



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